# **Surface Mount Schottky Power Rectifier**

**SMA Power Surface Mount Package** 

## MBRA130LT3G, NRVBA130LT3G, NRVBA130LN

This device employs the Schottky Barrier principle in a metal-to-silicon power rectifier. Features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies; free wheeling diodes and polarity protection diodes.

#### **Features**

- Compact Package with J-Bend Leads Ideal for Automated Handling
- Highly Stable Oxide Passivated Junction
- Guardring for Over-Voltage Protection
- Low Forward Voltage Drop
- NRVBA Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable\*
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Mechanical Characteristics:**

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 70 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Cathode Lead Indicated by Either Notch in Plastic Body or Polarity Band
- Device Meets MSL1 Requirements
- ESD Ratings:
  - Machine Model = C (> 400 V)
  - Human Body Model = 3B (> 8000 V)



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#### SCHOTTKY BARRIER RECTIFIER 1.0 AMPERES, 30 VOLTS



SMA CASE 403D PLASTIC

#### MARKING DIAGRAM



B1L3 = Specific Device Code A = Assembly Location\*\*\*

Y = Year WW = Work

Work WeekPb-Free Package

(Note: Microdot may be in either location)

\*\*\*The Assembly Location code (A) is front side optional. In cases where the Assembly Location is stamped in the package bottom (molding ejecter pin), the front side assembly code may be blank.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MBRA130LT3G	SMA (Pb-Free)	5,000 / Tape & Reel **
NRVBA130LT3G*	SMA (Pb-Free)	5,000 / Tape & Reel **
NRVBA130LNT3G*	SMA (Pb-Free)	5,000 / Tape & Reel **

<sup>\*\* 12</sup> mm Tape, 13" Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### MBRA130LT3G, NRVBA130LT3G, NRVBA130LN

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	V
Average Rectified Forward Current (At Rated $V_R$ , $T_C = 105$ °C)	lo	1.0	Α
Peak Repetitive Forward Current (At Rated $V_R$ , Square Wave, 100 kHz, $T_C$ = 105°C)	I <sub>FRM</sub>	2.0	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	25	Α
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C
Operating Junction Temperature	TJ	-55 to +125	°C
Voltage Rate of Change, (Rated V <sub>R</sub> , T <sub>J</sub> = 25°C)	dv/dt	10,000	V/μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance — Junction-to-Lead (Note 1) Thermal Resistance — Junction-to-Ambient (Note 1)	$R_{ hetaJL} \ R_{ hetaJA}$	35 86	°C/W

<sup>1.</sup> Mounted on 2" Square PC Board with 1" Square Total Pad Size, PC Board FR4.

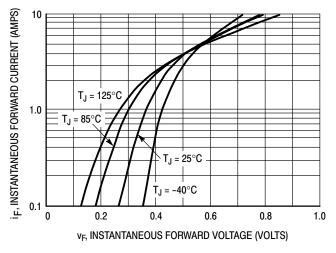
#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Va	Unit	
Maximum Instantaneous Forward Voltage (Note 2)	V <sub>F</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 100°C	Volts
(I <sub>F</sub> = 1.0 A) see Figure 2 (I <sub>F</sub> = 2.0 A)		0.41 0.47	0.35 0.43	
Maximum Instantaneous Reverse Current	I <sub>R</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 100°C	mA
(V <sub>R</sub> = 30 V) see Figure 4 (V <sub>R</sub> = 15 V)		1.0 0.4	25 12	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width  $\leq$  250  $\mu$ s, Duty Cycle  $\leq$  2.0%.

### MBRA130LT3G, NRVBA130LT3G, NRVBA130LN



1.0 T<sub>J</sub> =  $125^{\circ}$ C

T<sub>J</sub> =  $125^{\circ}$ C

T<sub>J</sub> =  $85^{\circ}$ C

T<sub>J</sub> =  $25^{\circ}$ C

V<sub>F</sub> MAXIMUM INSTANTANEOUS FORWARD VOLTAGE (VOLTS)

Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

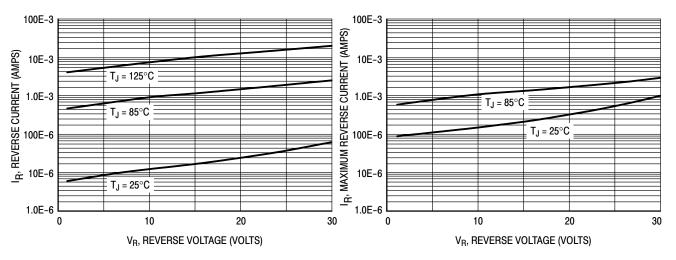
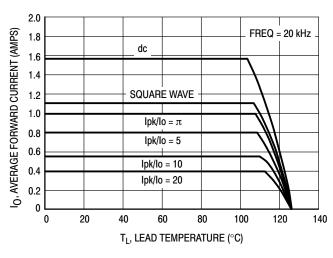


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current

### MBRA130LT3G, NRVBA130LT3G, NRVBA130LN



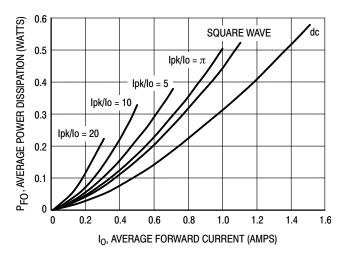


Figure 5. Current Derating

Figure 6. Forward Power Dissipation

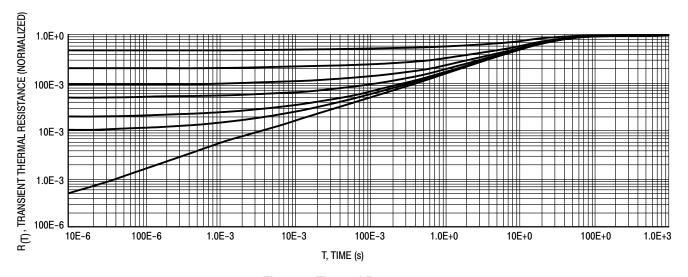


Figure 7. Thermal Response

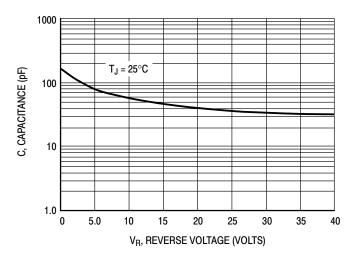


Figure 8. Capacitance

#### **MECHANICAL CASE OUTLINE**

PACKAGE DIMENSIONS





HE

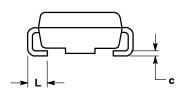
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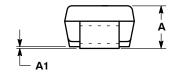
**SMA** CASE 403D ISSUE H

**DATE 23 SEP 2015** 

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,
- 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L.

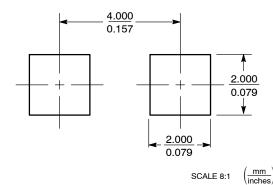
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.27	1.45	1.63	0.050	0.057	0.064
С	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
E	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060





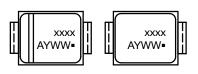
#### **SOLDERING FOOTPRINT\***

POLARITY INDICATOR OPTIONAL AS NEEDED (SEE STYLES)



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***



STYLE 1

STYLE 2

= Specific Device Code XXXX = Assembly Location Α

Υ = Year ww = Work Week = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1: PIN 1. CATHODE (POLARITY BAND)

STYLE 2: NO POLARITY

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